

Silicon PNP Power Transistor

2SA1695

DESCRIPTION

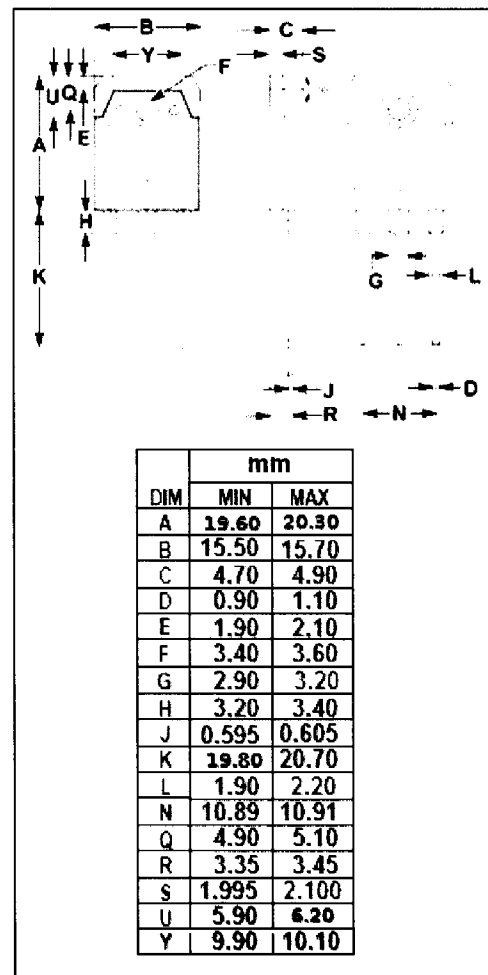
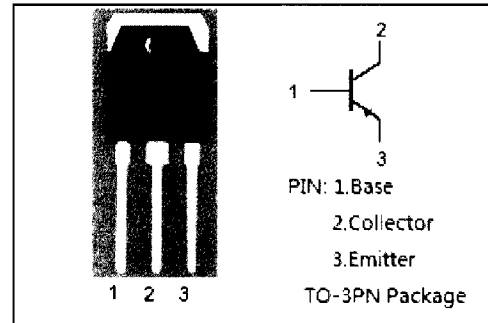
- Low Collector Saturation Voltage-
: $V_{CE(sat)} = -0.5V(\text{Min}) @ I_C = -5A$
- Good Linearity of h_{FE}
- Complement to Type 2SC4468

APPLICATIONS

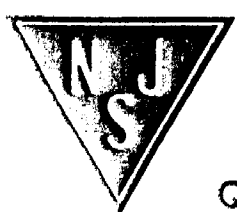
- Designed for audio and general purpose applications

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	-140	V
V_{CEO}	Collector-Emitter Voltage	-140	V
V_{EBO}	Emitter-Base Voltage	-6	V
I_C	Collector Current-Continuous	-10	A
I_B	Base Current-Continuous	-4	A
P_C	Collector Power Dissipation @ $T_C=25^\circ\text{C}$	100	W
T_J	Junction Temperature	150	°C
T_{stg}	Storage Temperature Range	-55~150	°C



NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.



Silicon PNP Power Transistor

2SA1695

ELECTRICAL CHARACTERISTICS

$T_C=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = -50\text{mA}; I_B = 0$	-140			V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -5.0\text{A}; I_B = -0.5\text{A}$			-0.5	V
I_{CBO}	Collector Cutoff Current	$V_{CB} = -140\text{V}; I_E = 0$			-10	μA
I_{EBO}	Emitter Cutoff Current	$V_{EB} = -6\text{V}; I_C = 0$			-10	μA
h_{FE}	DC Current Gain	$I_C = -3\text{A}; V_{CE} = -4\text{V}$	50		180	
C_{OB}	Output Capacitance	$I_E = 0; V_{CB} = -10\text{V}; f = 1.0\text{MHz}$		400		pF
f_T	Current-Gain—Bandwidth Product	$I_E = 0.5\text{A}; V_{CE} = -12\text{V}$		20		MHz

Switching times

t_{on}	Turn-on Time	$I_C = -5\text{A}, R_L = 12\Omega, I_{B1} = -I_{B2} = -0.5\text{A}, V_{CC} = -60\text{V}$		0.17		μs
t_{stg}	Storage Time			1.86		μs
t_f	Fall Time			0.27		μs

◆ h_{FE} Classifications

O	P	Y
50-100	70-140	90-180